2SA1501

Silicon PNP epitaxial planar type

For power switching

Features

- High-speed switching
- ullet High collector to base voltage V_{CBO}
- Wide area of safe operation (ASO)
- Satisfactory linearity of foward current transfer ratio h_{FE}
- Full-pack package which can be installed to the heat sink with one screw

Absolute Maximum Ratings (T_C=25°C)

| Symbol | Ratings | Unit |
|------------------|--|---|
| V_{CBO} | -400 | V |
| V _{CEO} | -400 | V |
| V_{EBO} | -7 | V |
| I_{CP} | -8 | A |
| I_{C} | -5 | A |
| D | 40 | ZZZ |
| P _C | 2.0 | W |
| T_j | 150 | °C |
| T_{stg} | -55 to +150 | °C |
| | V _{CBO} V _{CEO} V _{EBO} I _{CP} I _C T _j | $\begin{array}{c cccc} V_{CBO} & -400 \\ \hline V_{CEO} & -400 \\ \hline V_{CEO} & -400 \\ \hline V_{EBO} & -7 \\ \hline I_{CP} & -8 \\ \hline I_{C} & -5 \\ \hline P_{C} & 40 \\ \hline 2.0 \\ \hline T_{j} & 150 \\ \hline \end{array}$ |

Unit: mm 4.2±0.2 5.5±0.2 7.7±0.2 7.

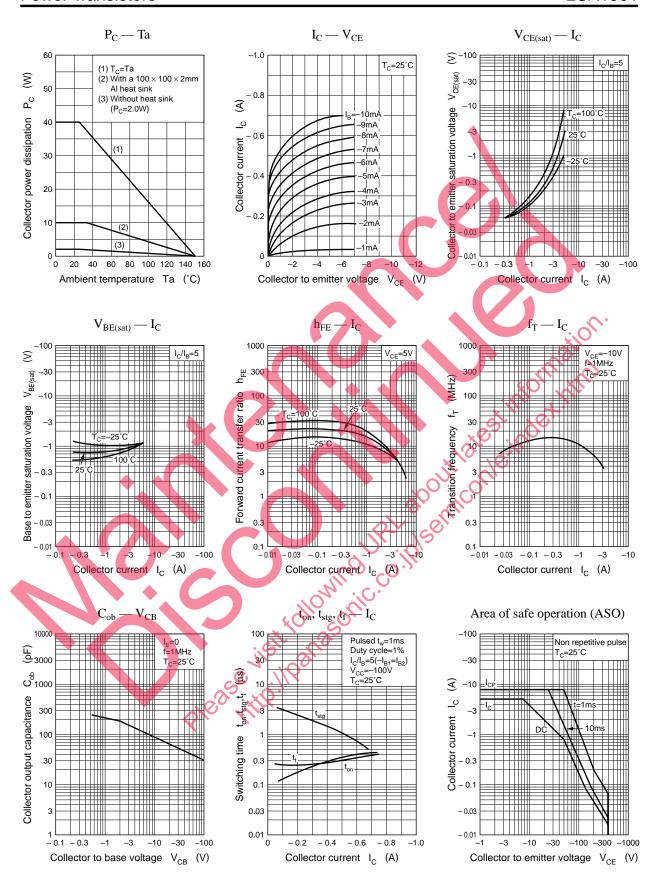
Electrical Characteristics (T_C=25°C)

| Parameter • | Symbol | Conditions | min | typ | max | Unit |
|---|----------------------|---|------|-----|------|------|
| Collector cutoff current | I_{CBO} | $V_{CB} = 400V, I_{B} = 0$ | | | -100 | μА |
| Emitter cutoff current | I_{EBO} | $V_{EB} = -7V, I_C = 0$ | | | -100 | μА |
| Collector to emitter voltage | V _{CEO} | $I_{\rm C} = -10 {\rm mA}, I_{\rm B} = 0$ | -400 | | | V |
| Forward current transfer ratio | h _{FE1} * | $V_{CE} = -5V, I_{C} = -0.5A$ | 20 | | 100 | |
| | h _{FE2} | $V_{CE} = -5V, I_{C} = -2A$ | 8 | | | |
| Collector to emitter saturation voltage | V _{CE(sat)} | $I_C = -2A, I_B = -0.4A$ | | | -1.0 | V |
| Base to emitter saturation voltage | V _{BE(sat)} | $I_C = -2A, I_B = -0.4A$ | | | -1.5 | V |
| Transition frequency | f_T | $V_{CE} = -10V, I_{C} = -0.5A, f = 1MHz$ | | 15 | | MHz |
| Turn-on time | t _{on} | $I_C = -2A$, | | | 1.0 | μs |
| Storage time | t _{stg} | $I_{B1} = -0.4A, I_{B2} = 0.4A,$ | | | 2.5 | μs |
| Fall time | $t_{\rm f}$ | $V_{CC} = -100V$ | | | 1.0 | μs |

*h_{FE1} Rank classification

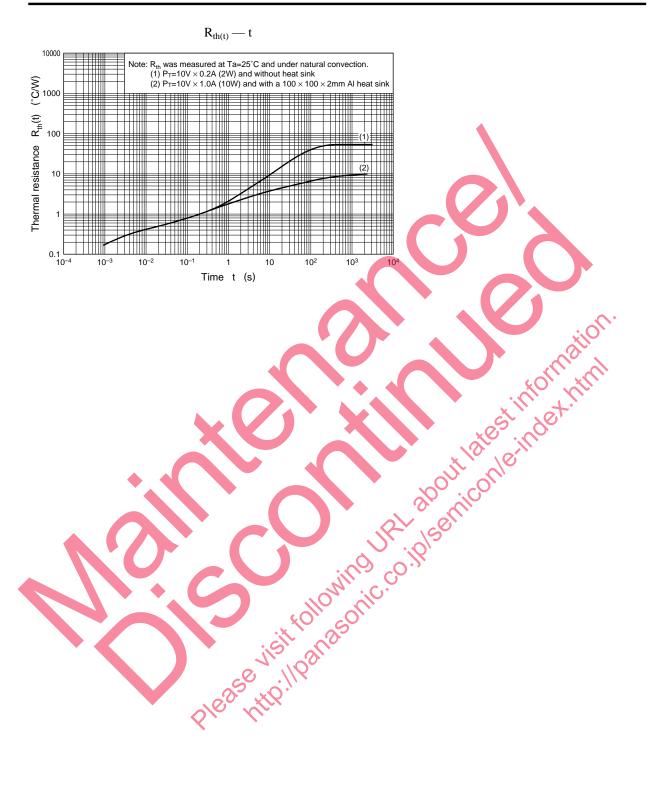
| Rank | Q | P |
|------------------|----------|-----------|
| h _{FE1} | 20 to 60 | 50 to 100 |

Power Transistors 2SA1501



2 Panasonic

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